Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.374 inches

Mounting Facility Quantity:

1

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.677 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

63.0 breakdown voltage, dc

Voltage Tolerance In Percent:

-5.0/+5.0

Current Rating Per Characteristic:

1.00 milliamperes forward current, average peak

Power Rating Per Characteristic:

15000.0 watts small-signal input power, common-collector pascal

Test Data Document:

06845-2079741 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0